

# **Technical Note**

# Secondary Variable Output LDO Regulator Series for Local Power Supplies



# **300mA Secondary Variable Output**

BD00GA3WEFJ

No.10026EAT05

# Description

BD00GA3WEFJ is a LDO regulator with output current 0.3A. The output accuracy is ±1% of output voltage. With external resistance, it is available to set the output voltage at random (from 1.5V to 13.0V) and also provides output voltage fixed type without external resistance. It is used for the wide applications of digital appliances. It has package type: HTSOP-J8. Over current protection (for protecting the IC destruction by output short circuit), circuit current ON/OFF switch (for setting the circuit 0µA at shutdown mode), and thermal shutdown circuit (for protecting IC from heat destruction by over load condition) are all built in. It is usable for ceramic capacitor and enables to improve smaller set and long-life.

# Features

- 1) Output current 0.3A
- 2) High accuracy reference voltage circuit
- 3) Built-in Over Current Protection circuit (OCP)
- 4) Built-in Thermal Shut Down circuit (TSD)
- 5) With shut down switch
- 6) Output voltage variable type (1.5V to 13.0V)
- 7) Package: HTSOP-J8

# Output voltage differential Line up

I	Product name	Variable	Package	
		variable	0	
	BD00GA3WEFJ	0	HTSOP-J8	
	Product name	: BD00	GA3WE	FJ

Signal		Desc	ription				
		Output voltage (V)					
а	C	0	Vari	able			
		Voltage re	sistance(V)				
h	E	24V	Н	10V			
b	F	20V	I	7V			
	G	15V					
		Output o	urrent (A)				
	A1	0.1A	C0	1.0A			
С	A3	0.3A	C5	1.5A			
	A5	0.5A	D0	2.0A			
		Shutdov	vn switch				
d	"\	V"	Shutdown switch is built in				
	"	"	Shutdown switch	is not built in			
		Pac	kage				
е	E	FJ	HTSC	OP-J8			

# ●Absolute Maximum Ratings (Ta=25°C)

Parame	eter	Symbol	Limits	Unit
Power supply voltage	e	Vcc	15.0 * <sup>1</sup>	V
EN voltage		V <sub>EN</sub>	15.0	V
Output voltage		Vout	15.0	V
Feedback voltage		V <sub>FB</sub>	15.0	V
Power dissipation	HTSOP-J8	Pd <sup>*2</sup>	2110 <sup>*2</sup>	mW
Operating Temperatu	ire Range	Topr	-25~+85	°C
Storage Temperature	Range	Tstg	-55~+150	°C
Junction Temperature	e	Tjmax	+150	C

\*1 Not to exceed Pd

\*2 Reduced by 16.9mW/°C for each increase in Ta of 1°C over 25°C. (when mounted on a board 70mm × 70mm × 1.6mm glass-epoxy board, two layer)

#### ●Operating conditions (Ta=25°C)

Parameter	Symbol	Min.	Max.	Unit
Input power supply voltage	Vcc	4.5	14.0	V
EN voltage	V <sub>EN</sub>	0.0	14.0	V
Output voltage setting range	Vo	1.5	13.0	V
Output current	lo	0.0	0.3	А

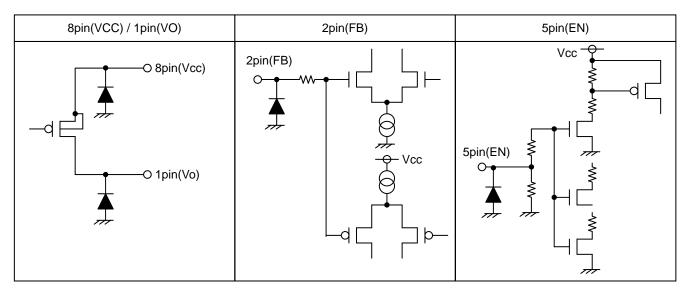
This product should not be used in a radioactive environment.

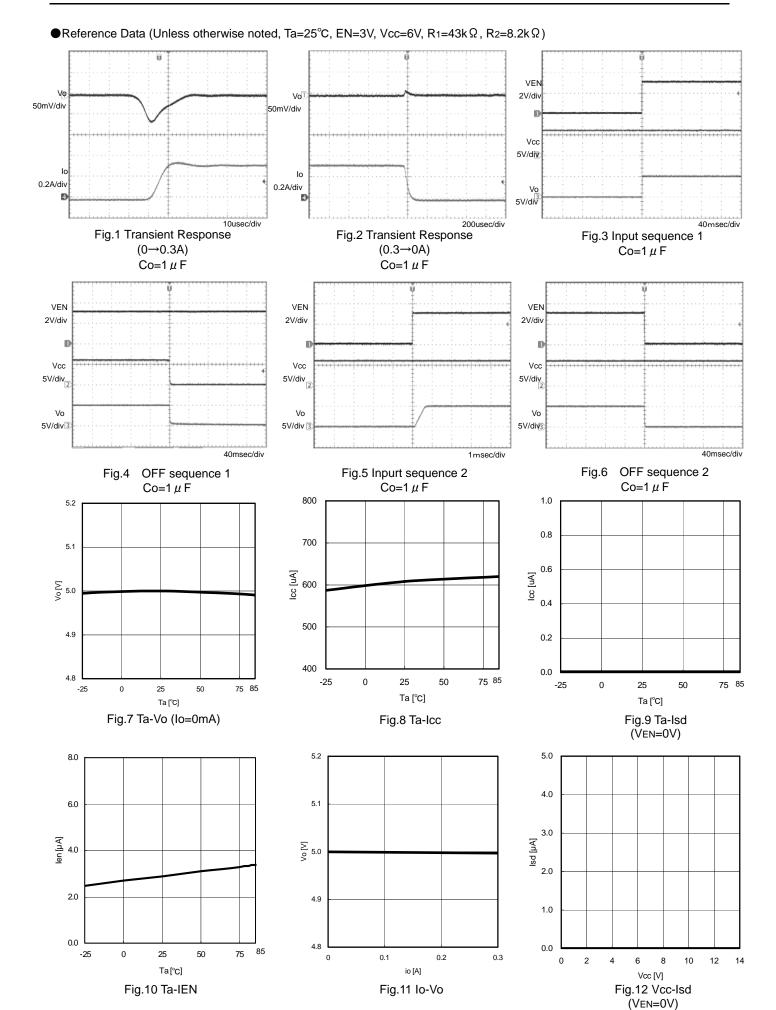
#### • Electrical Characteristics

(Unless otherwise noted, Ta=25°C, EN=3V, Vcc=6V, R1=43k $\Omega$ , R2=8.2k $\Omega$ )

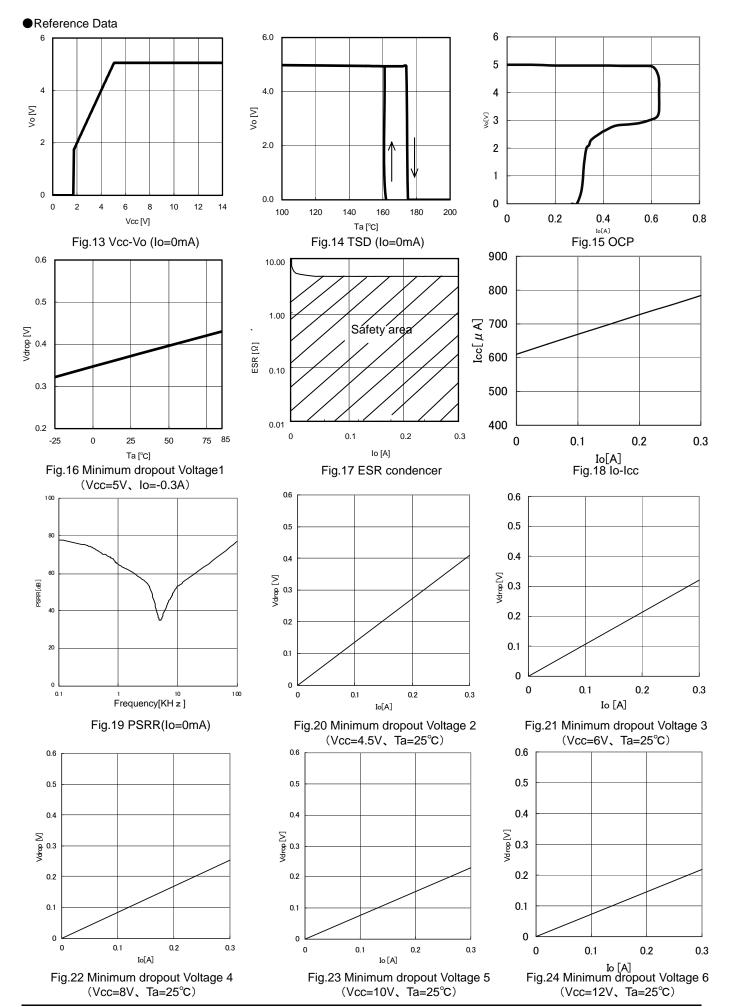
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Circuit current at shutdown mode	lsd	-	0	5	μA	EN=0V, OFF mode
Bias current	lcc	-	600	900	μΑ	
Line regulation	Reg.I	-	25	50	mV	Vcc=( Vo+0.9V )→14.0V
Load regulation	Reg lo	-	25	75	mV	lo=0→0.3A
Minimun dropout Voltage	Vco	-	0.6	0.9	V	Vcc=5V,Io=0.3A
Output reference voltage	V <sub>FB</sub>	0.792	0.800	0.808	V	lo=0mA
EN Low voltage	VEN (LOW)	0	-	0.8	V	
EN High voltage	VEN (High)	2.4	-	14.0	V	
EN Bias current	IEN	1	3	9	μA	

# ●I/O Equivalent circuits



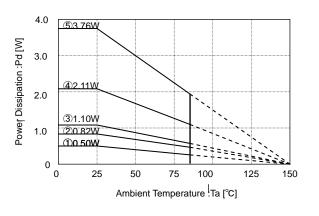


www.rohm.com © 2010 ROHM Co., Ltd. All rights reserved.



# Heat Dissipation Characteristics ØHTSOP-J8





Measure condition: mounted on a ROHM board, and IC

1 IC only

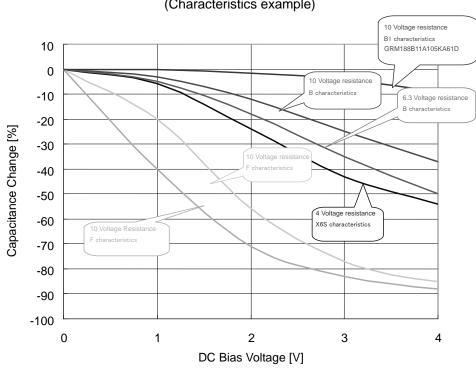
- *θ* j-a=249.5°C/W
- ② 1-layer (copper foil are :0mm × 0mm)  $\theta$  j-a=153.2°C/W
- (3) 2-layer (copper foil are :15mm × 15mm)  $\theta$  j-a=113.6°C/W
- (4) 2-layer (copper foil are :70mm × 70mm)  $\theta$  j-a=59.2°C/W
- (5) 4-layer (copper foil are :70mm × 70mm)  $\theta$  j-a=33.3°C/W

About Input-to-output capacitor

It is recommended that a capacitor is placed nearby pin between Input pin and GND, output pin and GND.

A capacitor, between input pin and GND, is valid when the power supply impedance is high or drawing is long. Also as for a capacitor, between output pin and GND, the greater the capacity, more sustainable the line regulation and it makes improvement of characteristics by load change. However, please check by mounted on a board for the actual application. Ceramic capacitor usually has difference, thermal characteristics and series bias characteristics, and moreover capacity decreases gradually by using conditions.

For more detail, please be sure to inquire the manufacturer, and select the best ceramic capacitor.



Ceramic capacitor capacity- DC bias characteristics (Characteristics example)

Substrate size: 70mm × 70mm × 1.6mm (Substrate with thermal via) • Solder the substrate and package reverse exposure heat radiation part

#### Heat Loss

Thermal design should allow operation within the following conditions. Note that the temperatures listed are the allowed temperature limits, and thermal design should allow sufficient margin from the limits.

- 1. Ambient temperature Ta can be no higher than 85°C.
- 2. Chip junction temperature (Tj) can be no higher than 150°C.

Chip junction temperature can be determined as follows:

① Calculation based on ambient temperature (Ta) Tj=Ta+ $\theta$ j-a×W

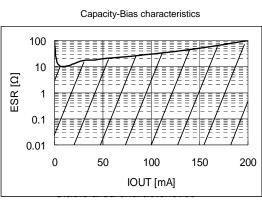
<Reference values>

Most of the heat loss that occurs in the BD00GA3WEFJ is generated from the output Pch FET. Power loss is determined by the total V<sub>cc</sub>-Vo voltage and output current. Be sure to confirm the system input and output voltage and the output current conditions in relation to the heat dissipation characteristics of the V<sub>IN</sub> and Vo in the design. Bearing in mind that heat dissipation may vary substantially depending on the substrate employed (due to the power package incorporated in the BD00GA3WEFJ make certain to factor conditions such as substrate size into the thermal design.

Power consumption (W) = 
$$\left\{ \text{ Input voltage (VCC)- Output voltage (Vo)} \right\} \times \text{Io(Ave)}$$
  
Example) Where VCC=5.0V, VO=3.3V, Io(Ave) = 0.1A,  
Power consumption (W) =  $\left\{ 5.0(V) - 3.3(V) \right\} \times 0.1(A)$   
=0.17(W)

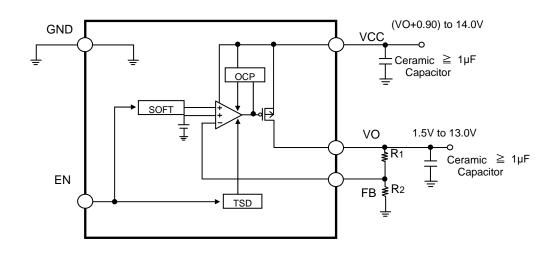
About equivalent series resistance ESR (ceramic capacitor etc.)

Capacitor usually has ESR (Equivalent Series Resistance), and operates stable in ESR-OUT range, showed right. Generally, ESR of ceramic, tantalum and electronic capacitor etc. is different for each, so please be sure to check a capacitor which is going to use, and use it inside the stable range, showed right. Then, please evaluate for the actual application.



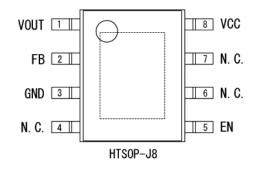
(Characteristics example)

# Block Diagram BD00GA3WEFJ



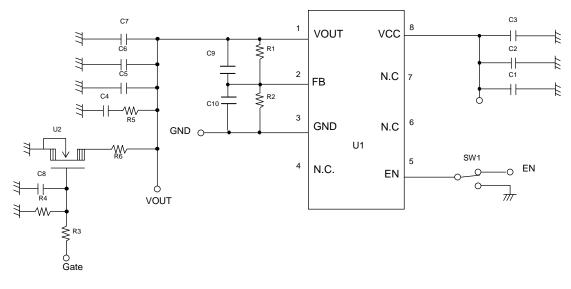
# ●Pin number • Pin name

Pin No.	Pin name	Pin Function	
1	VOUT	Output voltage pin	
2	FB	Feedback pin	
3	GND	GND pin	
4	N.C.	Non Connection	
5	EN	Enable pin	
6	N.C.	Non Connection	
7	N.C.	Non Connection	
8	VCC	Input voltage pin	
Reverse	FIN	Substrate(GND pin)	



7/11

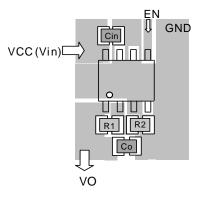
# Evaluation Board Circuit



# •Evaluation Board Parts List

Designation	Value	Part No.	Company	Designation	Value	Part No.	Company
R1	43k Ω	MCR01PZPZF4302	ROHM	C4	-	-	-
R2	8.2kΩ	MCR01PZPZF8201	ROHM	C5	1uF	CM105B105K16A	KYOCERA
R3	-	-	-	C6			
R4	-	-	-	C7	-	-	-
R5	-	-	-	C8	-	-	-
R6	-	-	-	C9	-	-	-
C1	1uF	CM105B105K16A	KYOCERA	C10	-	-	-
C2	-	-		U1	-	BD00GA3WEFJ	ROHM
C3	-	-		U2	-	-	-

#### About Board Layout



- Input capacitor Cin of VCC (Vin) should be placed very close to VCC(Vin) pin as possible, and used broad wiring pattern.
   Output capacitor Co also should be placed close to IC pin as possible. In case connected to inner layer GND plane, please use several through hole.
- VFB pin has comparatively high impedance, and is apt to be effected by noise, so floating capacity should be minimum as possible. Please be careful in wiring drawing

• Please take GND pattern space widely, and design layout to be able to increase radiation efficiency.

· For output voltage setting

Output voltage can be set by FB pin voltage (0.800V typ.) and external resistance R1, R2.

$$VO = VFB \times \frac{R_{1}+R_{2}}{R_{2}}$$

(The use of resistors with R1+R2=5k to 90k is recommended)

# Operation Notes

#### (1). Absolute maximum ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

#### (2). Connecting the power supply connector backward

Connecting of the power supply in reverse polarity can damage IC. Take precautions when connecting the power supply lines. An external direction diode can be added.

# (3). Power supply lines

Design PCB layout pattern to provide low impedance GND and supply lines. To obtain a low noise ground and supply line, separate the ground section and supply lines of the digital and analog blocks. Furthermore, for all power supply terminals to ICs, connect a capacitor between the power supply and the GND terminal. When applying electrolytic capacitors in the circuit, not that capacitance characteristic values are reduced at low temperatures.

#### (4). GND voltage

The potential of GND pin must be minimum potential in all operating conditions.

#### (5). Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

#### (6). Inter-pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.

#### (7). Actions in strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

#### (8). ASO

When using the IC, set the output transistor so that it does not exceed absolute maximum ratings or ASO.

# (9). Thermal shutdown circuit

The IC incorporates a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent thermal runaway. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of this circuit is assumed.

	TSD ON Temperature[°C] (typ.)	Hysteresis Temperature [°C] (typ.)
BD00GA3WEFJ	175	15

# (10). Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting or storing the IC.

# (11). Regarding input pin of the IC

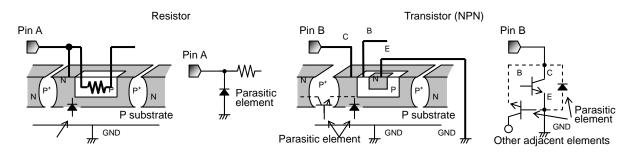
This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, the relation between each potential is as follows:

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes can occur inevitable in the structure of the IC.

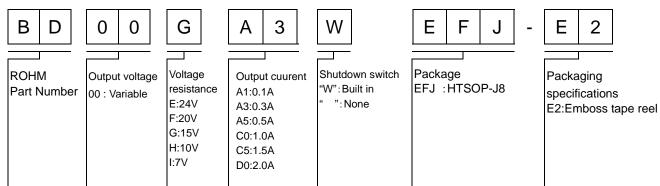
The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.



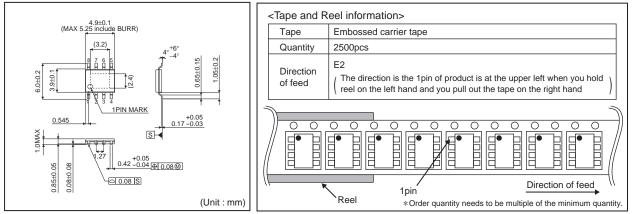
#### (12). Ground Wiring Pattern.

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the ground potential of application so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

# Type Designations (Ordering Information)



# **HTSOP-J8**



	opying or reproduction of this document, in part or in whole, is permitted without th
cons	ent of ROHM Co.,Ltd.
The o	content specified herein is subject to change for improvement without notice.
"Proc	content specified herein is for the purpose of introducing ROHM's products (hereinafte ducts"). If you wish to use any such Product, please be sure to refer to the specifications h can be obtained from ROHM upon request.
illust	nples of application circuits, circuit constants and any other information contained herei rate the standard usage and operations of the Products. The peripheral conditions musken into account when designing circuits for mass production.
How	t care was taken in ensuring the accuracy of the information specified in this documen- ever, should you incur any damage arising from any inaccuracy or misprint of suc mation, ROHM shall bear no responsibility for such damage.
exarr impli other	echnical information specified herein is intended only to show the typical functions of an aples of application circuits for the Products. ROHM does not grant you, explicitly of citly, any license to use or exercise intellectual property or other rights held by ROHM an or parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the of such technical information.
equip	Products specified in this document are intended to be used with general-use electroni oment or devices (such as audio visual equipment, office-automation equipment, commu ion devices, electronic appliances and amusement devices).
The F	Products specified in this document are not designed to be radiation tolerant.
	e ROHM always makes efforts to enhance the quality and reliability of its Products, uct may fail or malfunction for a variety of reasons.
agair failur shall	se be sure to implement in your equipment using the Products safety measures to guar not the possibility of physical injury, fire or any other damage caused in the event of th e of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHN bear no responsibility whatsoever for your use of any Product outside of the prescriber e or not in accordance with the instruction manual.
syste may instru contr of th	Products are not designed or manufactured to be used with any equipment, device of em which requires an extremely high level of reliability the failure or malfunction of whic result in a direct threat to human life or create a risk of human injury (such as a medica ument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel- roller or other safety device). ROHM shall bear no responsibility in any way for use of an e Products for the above special purposes. If a Product is intended to be used for an special purpose, please contact a ROHM sales representative before purchasing.
be co	u intend to export or ship overseas any Product or technology specified herein that ma ontrolled under the Foreign Exchange and the Foreign Trade Law, you will be required t n a license or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

# ROHM Customer Support System

http://www.rohm.com/contact/